


Chapter 4: Imperfections in Solids

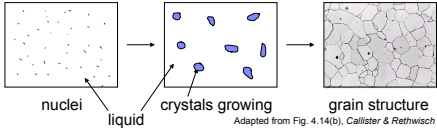
ISSUES TO ADDRESS...

- What are the solidification mechanisms?
- What types of defects arise in solids?
- Can the number and type of defects be varied and controlled?
- How do defects affect material properties?
- Are defects undesirable?

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Imperfections in Solids

- _____ - result of casting of molten material
 - 2 steps
 - _____ form
 - _____ grow to form crystals - _____
- Start with a _____ material - all liquid



Adapted from Fig. 4.14(b), Callister & Rethwisch 8e.

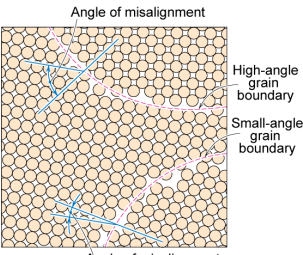
- _____ grow until they meet each other

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Polycrystalline Materials

Grain Boundaries

- regions between _____
- transition from _____ of one region to that of the other
- slightly _____
- low density in grain boundaries
 - high _____
 - high _____
 - high chemical reactivity



Adapted from Fig. 4.7, Callister & Rethwisch 8e.

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Solidification

Grains can be - _____ (roughly same size in all directions)
 - _____ (elongated grains)
 ~ 8 cm

Columnar in area with less undercooling

Shell of _____ grains due to rapid cooling (greater ΔT) near wall

Adapted from Fig. 5.17, Callister & Rethwisch 3e.

Grain Refiner - added to make smaller, more uniform, equiaxed grains.

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Imperfections in Solids

There is no such thing as a perfect crystal.

- What are these imperfections?
- Why are they important?

Many of the important properties of materials are due to the presence of imperfections.

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Types of Imperfections

- Vacancy atoms
- Interstitial atoms
- Substitutional atoms

| _____ defects

- Dislocations

| _____ defects

- Grain Boundaries

| Area defects

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Point Defects in Metals

- Vacancies:**
-vacant _____ sites in a structure.

distortion of planes

- Self-_____:**
-"extra" atoms positioned between _____ sites.

self-interstitial

distortion of planes

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Equilibrium Concentration: Point Defects

- Equilibrium _____ varies with temperature!

No. of defects N_V energy

No. of potential defect sites N $\rightarrow N_V = \exp\left(\frac{-Q_V}{kT}\right)$

Boltzmann's constant k

(1.38 x 10⁻²³ J/atom-K)
(8.62 x 10⁻⁵ eV/atom-K)

Each _____ site is a potential vacancy site

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Measuring Activation Energy

- We can get Q_V from an experiment.
- Measure this... $\frac{N_V}{N} = \exp\left(\frac{-Q_V}{kT}\right)$
- Replot it... $\ln \frac{N_V}{N}$

defect _____

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Estimating Vacancy Concentration

- Find the equil. # of vacancies in 1 m³ of Cu at 1000°C.
- Given:
 - $\rho = \text{_____}$ $A_{Cu} = \text{_____}$
 - $Q_v = 0.9 \text{ eV/atom}$ $N_A = 6.02 \times 10^{23} \text{ atoms/mol}$

$$\frac{N_v}{N} = \exp\left(\frac{-Q_v}{kT}\right) = 2.7 \times 10^{-4}$$

0.9 eV/atom (red arrow pointing to $-Q_v$)
 1273 K (green arrow pointing to T)
 $8.62 \times 10^{-5} \text{ eV/atom-K}$ (green arrow pointing to k)

For 1 m³, $N = \rho \times \frac{N_A}{A_{Cu}} \times 1 \text{ m}^3 = 8.0 \times 10^{28} \text{ sites}$


- Answer:
 - $N_v = (2.7 \times 10^{-4})(8.0 \times 10^{28}) \text{ sites} = 2.2 \times 10^{25} \text{ vacancies}$

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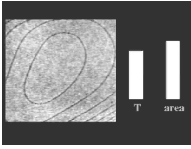
Observing Equilibrium Vacancy Conc.

- Low energy electron _____ view of a (110) surface of NiAl.
- Increasing _____ causes surface island of atoms to grow.
- Why? The equil. vacancy conc. _____ via atom motion from the crystal to the surface, where they join the island.

Island grows/shrinks to maintain equil. vacancy conc. in the bulk.



Click once on image to start animation




Reprinted with permission from Nature (K.F. McCarthy, J.A. Nobel, and N.C. Bartelt, "Vacancies in Solids and the Stability of Surface Morphology", Nature, Vol. 412, pp. 622-625 (2001). Image is 5.75 μm by 5.75 μm.) Copyright (2001) Macmillan Publishers, Ltd.

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Imperfections in Metals (i)

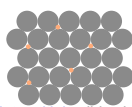
Two outcomes if impurity (B) added to host (A):

- _____ of B in A (i.e., _____ dist. of point defects)




Substitutional solid soln.
(e.g., Cu in Ni)

OR



Interstitial solid soln.
(e.g., C in Fe)

- Solid solution of B in A plus _____ of a new phase (usually for a larger amount of B)



Second phase particle
 -- different _____
 -- often different structure.

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Imperfections in Metals (ii)

Conditions for _____ solid solution (S.S.)

- **W. Hume – Rothery rule**

- 1. Δr (atomic radius) < 15%
- 2. Proximity in _____ table
 - i.e., similar electronegativities
- 3. Same crystal _____ for pure metals
- 4. Valency
 - All else being equal, a metal will have a greater tendency to dissolve a metal of higher valency than one of lower valency

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Imperfections in Metals (iii)


Application of Hume–Rothery rules – Solid Solutions

1. Would you predict more Al or Ag to dissolve in Zn?

2. More Zn or Al in Cu?

Element	Atomic Radius (nm)	Crystal Structure	Electronegativity	Valence
Cu	0.1278	FCC	1.9	+2
C	0.071			
H	0.046			
O	0.060			
Ag	0.1445	FCC	1.9	+1
Al	0.1431	FCC	1.5	+3
Co	0.1253	HCP	1.8	+2
Cr	0.1249	BCC	1.6	+3
Fe	0.1241	BCC	1.8	+2
Ni	0.1246	FCC	1.8	+2
Pd	0.1376	FCC	2.2	+2
Zn	0.1332	HCP	1.6	+2

Table on p. 118, Callister & Rethwisch 9e.

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Impurities in Solids


- Specification of composition

– weight percent $C_1 = \frac{m_1}{m_1 + m_2} \times 100$

m_1 = mass of component 1

– atom percent $C_1 = \frac{n_{m1}}{n_{m1} + n_{m2}} \times 100$

n_{m1} = number of moles of component 1

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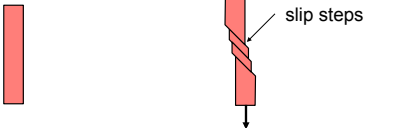
Line Defects


Dislocations:

- are line defects,
- slip between crystal planes result when _____ move,
- produce permanent (plastic) _____.

Schematic of Zinc (HCP):

- before deformation
- after tensile _____



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Imperfections in Solids

Linear Defects (_____)

- Are one-dimensional defects around which atoms are misaligned

- **Edge _____:**
 - extra half-plane of atoms inserted in a crystal _____
 - **b** perpendicular (\perp) to dislocation line
- **Screw dislocation:**
 - _____ ramp resulting from shear deformation
 - **b** parallel (\parallel) to dislocation line

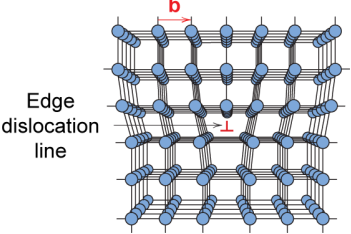
Burger's vector, **b**: measure of _____ distortion

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Imperfections in Solids


Edge Dislocation

Burgers vector



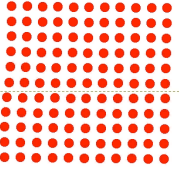
Edge dislocation line

Fig. 4.3, Callister & Rethwisch 8e.

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Motion of Edge Dislocation

- _____ motion requires the successive bumping of a half plane of atoms (from left to right here).
- Bonds across the slipping _____ are broken and remade in succession.



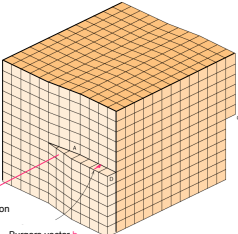
Click once on image to start animation
(Courtesy P.M. Anderson)

Atomic view of edge dislocation motion from left to right as a crystal is sheared.

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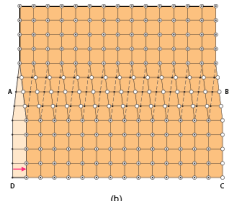
Imperfections in Solids

Screw Dislocation




Dislocation line
Burgers vector b

(a)



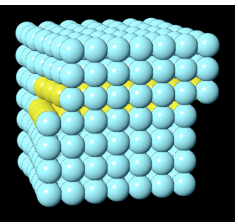
(b)

Adapted from Fig. 4.4, Callister & Rethwisch 8e.

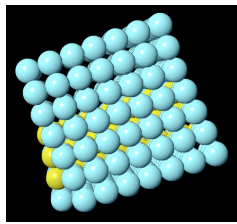
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VMSE: Screw Dislocation

- In VMSE:
 - a region of crystal containing a dislocation can be rotated in 3D
 - dislocation motion may be animated




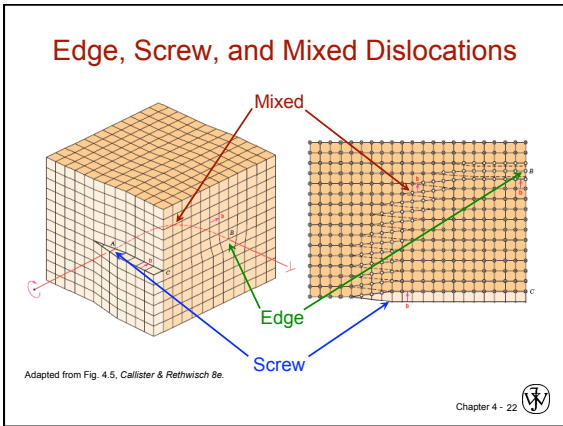
Front View

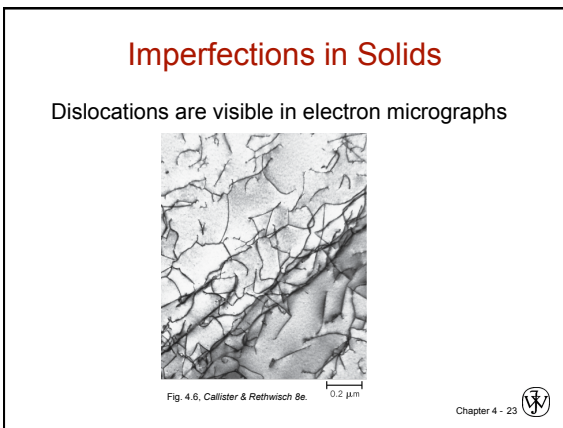


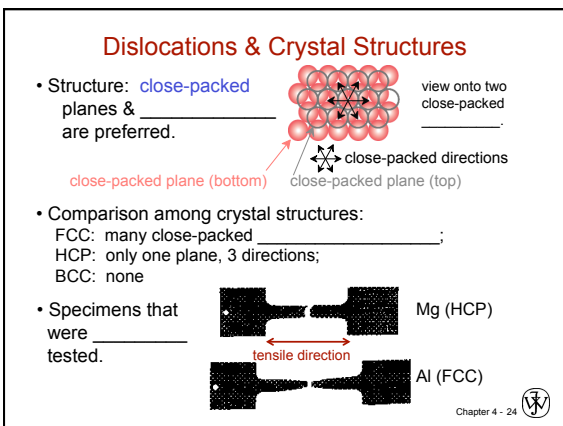
Top View

VMSE Screen Shots

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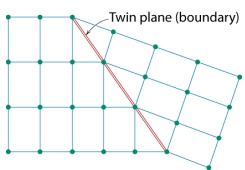







Planar Defects in Solids

- One case is a **twin boundary (plane)**
 - Essentially a reflection of atom positions across the **twin plane**.



Adapted from Fig. 4.9, Callister & Rethwisch 8e.

- Stacking faults**
 - For FCC metals an error in ABCABC packing sequence
 - Ex: ABCABABC

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Catalysts and Surface Defects

- A **catalyst** increases the rate of a _____ without being consumed
- _____ on catalysts are normally surface defects

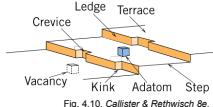


Fig. 4.10, Callister & Rethwisch 8e.

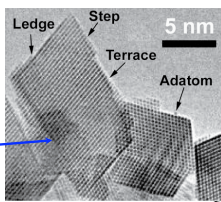




Fig. 4.11, Callister & Rethwisch 8e.
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Single crystals of $(Ce_{0.5}Zr_{0.5})O_2$ used in an automotive catalytic converter

Microscopic Examination

- _____ (grains) and grain boundaries. Vary considerably in size. Can be quite large.
 - ex: Large single crystal of quartz or _____ or Si
 - ex: Aluminum light post or garbage can - see the individual grains
- Crystallites (grains) can be quite small (mm or less) – necessary to observe with a _____.

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Optical Microscopy

- Useful up to _____ magnification.
- _____ removes surface features (e.g., scratches)
- Etching changes _____, depending on crystal orientation.

Adapted from Fig. 4.13(b) and (c), Callister & Rethwisch 9e. (Fig. 4.13(c) is courtesy of J.E. Burke, General Electric Co.)

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Optical Microscopy

Grain boundaries...

- are _____,
- are more susceptible to etching,
- may be revealed as dark lines,
- change in _____ orientation across boundary.

Adapted from Fig. 4.14(a) and (b), Callister & Rethwisch 9e. (Fig. 4.14(b) is courtesy of L.C. Smith and C. Brady, the National Bureau of Standards, Washington, DC [now the National Institute of Standards and Technology, Gaithersburg, MD].)

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ASTM grain size number

$$N = 2^{n-1}$$

_____ of grains/in²
at 100x magnification

Optical Microscopy

- Polarized light
 - metallographic scopes often use polarized light to increase contrast
 - Also used for transparent samples such as polymers

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Microscopy

Optical _____ ca. 10^{-7} m = 0.1 μ m = 100 nm

For higher resolution need higher _____

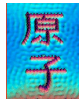
- X-Rays? Difficult to focus.
- Electrons
 - wavelengths ca. 3 pm (0.003 nm)
 - (Magnification - 1,000,000X)
 - _____ resolution possible
 - Electron beam focused by _____ lenses.

Scanning Tunneling Microscopy (STM)

- Atoms can be arranged and imaged!



Carbon monoxide molecules arranged on a platinum (111) surface.



Iron atoms arranged on a copper (111) surface. These Kanji characters represent the word "atom".

Photos produced from the work of C.P. Lutz, Zeppenfeld, and D.M. Eigler. Reprinted with permission from International Business Machines Corporation, copyright 1995.

Summary

- Point, Line, and Area defects exist in solids.
- The number and type of defects can be varied and controlled (e.g., T controls vacancy conc.)
- Defects affect material properties (e.g., grain boundaries control crystal slip).
- Defects may be desirable or undesirable (e.g., dislocations may be good or bad, depending on whether plastic deformation is desirable or not.)
